

FORM PTO-1449 INFORMATION DISCLOSURE STATEMENT	Atty. Docket: OKI 364	Application No.: Not yet assigned 10/630,869
	Applicant: Kojo KAJITA	
	Filing Date: July 31, 2003	Group Art Unit: 2818 Not yet assigned

U.S. PATENT DOCUMENTS

Examiner Initial		Document Number	Date	Name	Class	Sub-Class	Filing Date
	AA						
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						

FOREIGN PATENT DOCUMENTS

		Document Number	Date	Country	Class	Sub-Class	Translation
PD	AI	2001-257357	09/21/01	Japan			Abstract
	AJ						
	AK						
	AL						
	AM						

OTHER (Including Author, Title, Date, Pertinent Pages, etc.)

PD	AN	Recessed-Channel Structure for Fabricating Ultrathin SOI MOSFET with Low Series Resistance, Mansun Chan, Fariborz Assaderaghi, Stephen A. Parke, Chenming Hu, <i>Fellow</i> , IEEE, and Ping K. Ko, <i>Senior Member</i> , IEEE IEEE Electron Device Letter, Vol. 15, No. 1, January 1994
Examiner	PHUC T. DANG	
Date Considered	2/23/04	

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.